

Institute of Materials - Institute of Bioengineering sunmil.epfl.ch



Interfacial Phenomena Lesson 5

MSE 304

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Key Topics in the Previous Class



Phase Equilibrium: a Key Summary



The Chemical Potential of a Phase of Finite Size



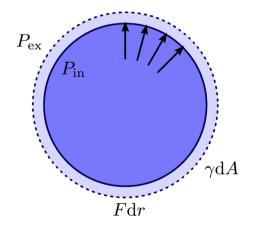
Size Dependence of a Generic Phase Transition



Laplace Pressure

- The surface energy term for a spherical droplet leads to a force acting perpendicular to the surface
- This force must be balanced by a pressure difference between the inside and the outside of the droplet
- Pressure for a water droplet: $1mm \rightarrow 0.001atm$; $1nm \rightarrow 1000atm$!

$$P_{\mathsf{in}} - P_{\mathsf{ex}} = \Delta P = F/A = 8\pi \gamma_{\mathsf{LV}} \mathit{\Gamma}/A = rac{2\gamma_{\mathsf{LV}}}{\mathit{\Gamma}}$$





Kelvin's Equation



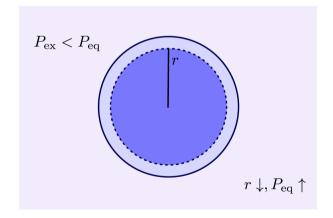
Ostwald Ripening

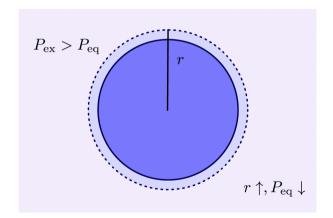


Stability of a Droplet

$$\boxed{\ln \frac{P_{\rm eq}}{P_0} = \frac{2\gamma_{\rm LV}V_{\rm in}}{RT}\frac{1}{r_{\rm eq}}}$$
 Kelvin Equation

• Every droplet in equilibrium with a constant-pressure vapor reservoir is in unstable equilibrium







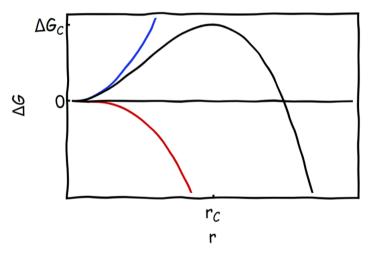
Nucleation and Growth: Outline



Nucleation and Growth: First Approach

$$\Delta G(r) = -\frac{4}{3}\pi r^3 \Delta G_{\mathsf{SL}} + 4\pi r^2 \gamma_{\mathsf{SL}}$$

$$\frac{\partial}{\partial \mathbf{r}} \Delta \mathbf{G} \left(\mathbf{r} \right) = \mathbf{0} \ \rightarrow \ \mathbf{r}_{c} = \frac{2 \gamma_{SL}}{\Delta \mathbf{G}_{SL}}, \ \Delta \mathbf{G} \left(\mathbf{r}_{c} \right) = \frac{16 \pi}{3} \frac{\gamma_{SL}^{3}}{\Delta \mathbf{G}_{SL}^{2}}$$



Nucleation and Growth: Second Approach

$$\Delta G_f^0 = (\mu_l - \mu_v) n$$

Where

 μ_l is the liquid chemical potential and μ_v is the solid chemical potential

Assuming an ideal vapor we can write

$$(\mu_l - \mu_v)n = -nk_B T \ln S$$

Where k_B is the Boltzmann constant and S, the supersaturation parameter, is the ratio between the vapor pressure P and the saturation equilibrium vapor pressure P_e

$$S = P/P_e$$

Nucleation and Growth: Second Approach

This contribution will always be favorable to cluster formation for the materials we are interested in.

At the same time when generating a drop we always are generating a new surface. The surface free energy will always be a destabilizing factor.

It can be shown that this energy is:

$$\gamma_s^0 = \gamma_{LV} * Area = \gamma_{LV} * 4\pi \left(\frac{3v}{4\pi}\right)^{\frac{2}{3}} n^{\frac{2}{3}}$$

 γ_{IV} = interfacial energy per unit area

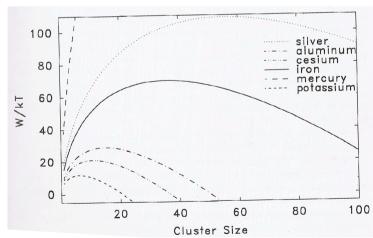
 $v = volume \ of \ an \ atom$

n = number of atoms

It should be obvious by looking at the equation just written that the total free energy of formation of for this droplet of material depends on the number of atoms that compose the droplet. In fact:

$$\Delta G = W(n) = -nk_B T \ln S + \gamma_{LV} 4\pi \left(\frac{3v}{4\pi}\right)^{\frac{2}{3}} n^{\frac{2}{3}}$$

The free energy can be seen as the reversible work made to form a cluster of n atoms.



Nucleation and Growth: Second Approach

The smallest cluster size (n^{*}) at which this happens is given by solving the equation

$$\frac{\partial W}{\partial n} = 0$$

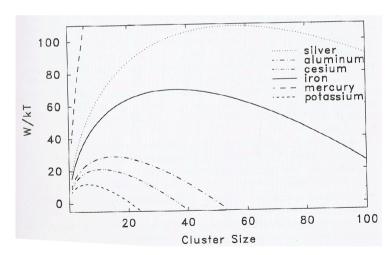
It can be shown that:

$$n^* = \frac{32\pi\sigma^3 v^2}{3(k_B T \ln S)^3}$$
$$r^* = \frac{2\sigma v}{3(k_B T \ln S)^3}$$

The value $W(n^*)$ is often referred as the barrier height for nucleation or nucleation energy.

Its value is:

$$W(n^*) = \frac{16\pi\sigma^3 v^2}{3(k_B T \ln S)^2}$$



Let's consider a solution containing molecules that form aggregates of various sizes. We will identify each aggregate with a number N that indicated the number of molecule that are in that aggregate. 1= single molecule, 2= dimer, 3= trimer, etc.

We can then define X_N as the dimensionless molar fraction of molecules that are in solution as the N^{th} aggregate. (Molar fraction = moles of X in 1L/ total moles in 1L, for aqueous solution take molar concentration and divide by 55.5)

NOTE that $X_N \le 1$ by definition

If we call C as the total molar fraction at any time the following equation has to be verified:

$$C = X_1 + X_2 + X_3 + + X_N = \sum_{N=1}^{\infty} X_N$$

The molar fraction (i.e. the concentration) of the N^{th} aggregate will be X_N/N

For this solution to be in equilibrium the condition to be met is that the chemical potential of each species present in solution has to be identical.

This equilibrium condition will determine the concentration of the various species

$$\mu = \mu_N^0 + \frac{kT}{N} \ln \left(\frac{X_N}{N} \right) = \cos \tan t = \mu_1^0 + kT \ln \left(X_1 \right)$$



Our main equation is:

$$\mu_N^0 + \frac{kT}{N} \ln \left(\frac{X_N}{N} \right) = \mu_1^0 + kT \ln \left(X_1 \right)$$

If we rewrite it in more general terms

$$\mu_N^0 + \frac{kT}{N} \ln \left(\frac{X_N}{N} \right) = \mu_M^0 + \frac{kT}{M} \ln \left(\frac{X_M}{M} \right)$$

and solve for X_N

We find

$$X_{N} = N \left\{ \frac{X_{M}}{M} \exp \left[\frac{M \left(\mu_{M}^{0} - \mu_{N}^{0} \right)}{kT} \right] \right\}^{\frac{N}{M}}$$

That gives the concentration of molecules in the Nth aggregate as a function of the concentration of molecule in the Mth aggregate.

In particular we can rewrite this for M=1

$$X_N = N \left\{ X_1 \exp\left[\frac{\left(\mu_1^0 - \mu_N^0\right)}{kT}\right] \right\}^N$$



$$X_{N} = N \left\{ X_{1} \exp \left[\frac{\left(\mu_{1}^{0} - \mu_{N}^{0} \right)}{kT} \right] \right\}^{N}$$

There is one necessary condition for the formation of aggregates: μ_N^0 has to change as a function of N. If that doesn't happen

$$X_N = NX_1^N$$

Since X₁<1, X_N<<1

Let's look now at a chain of N molecules in which the bond energy is αkT the total free energy of such a molecule will be $N\mu_{\scriptscriptstyle N}^0$

Thus

$$N\mu_N^0 = -(N-1)\alpha kT$$

$$\mu_N^0 = -\left(1 - \frac{1}{N}\right) \alpha kT = \mu_\infty^0 + \frac{\alpha kT}{N}$$

In this case $\mu_{\scriptscriptstyle N}^0$ decreases with N and converges asymptotically to the bulk value.

It can be shown that for a disc the equation becomes:

$$\mu_N^0 = \mu_\infty^0 + \frac{\alpha kT}{N^{\frac{1}{2}}}$$

For a sphere:

$$\mu_N^0 = \mu_\infty^0 + \frac{\alpha kT}{N^{\frac{1}{3}}}$$

More in general we can write:

$$\mu_N^0 = \mu_\infty^0 + \frac{\alpha kT}{N^p}$$

If we now substitute this equation in

$$X_N = N \left\{ X_1 \exp\left[\frac{\left(\mu_1^0 - \mu_N^0\right)}{kT}\right] \right\}^N$$

we get

$$X_{N} = N \left\{ X_{1} \exp \left[\frac{\left(\mu_{1}^{0} - \mu_{N}^{0} \right)}{kT} \right] \right\}^{N} = N \left\{ X_{1} \exp \left[\alpha \left(1 - \frac{1}{N^{p}} \right) \right] \right\}^{N} = N \left\{ X_{1} \exp \left[\alpha \right] \right\}^{N} \exp \left[\alpha N^{1-p} \right] \right\}$$

But X_N cannot exceed 1 thus there is a concentration of X_1 called *critical micelle concentration* (CMC) at which X_1 cannot grow more and larger aggregates have to form. Such concentration is

$$(X_1)_{crit} = CMC \approx \exp{-\left[\frac{(\mu_1^0 - \mu_N^0)}{kT}\right]}$$

At the critical concentration:

$$X_{N} = N \left\{ X_{1}^{crit} \exp \left[\alpha\right] \right\}^{V} \exp \left[\alpha N^{1-p}\right]$$



$$(X_1)_{crit} = CMC \approx \exp{-\left[\frac{(\mu_1^0 - \mu_N^0)}{kT}\right]}$$

At the critical concentration:

$$X_{N} = N \left\{ X_{1}^{crit} \exp \left[\alpha\right] \right\}^{V} \exp \left[\alpha N^{1-p}\right]$$



$$X_N = N \left\{ X_1 \exp \left[\frac{\left(\mu_1^0 - \mu_N^0 \right)}{kT} \right] \right\}^N$$

In that can we can expand around that minimum:

$$\mu_N^0 - \mu_M^0 = \Lambda (\Delta N)^2$$

Then:

$$X_{N} = N \left\{ \frac{X_{M}}{M} \exp \left[\frac{M \left(\mu_{M}^{0} - \mu_{N}^{0} \right)}{kT} \right] \right\}^{\frac{N}{M}} = N \left\{ \frac{X_{M}}{M} \exp \left[\frac{M \Lambda \left(\Delta N \right)^{2}}{kT} \right] \right\}^{\frac{N}{M}}$$

Nearly a Gauss



Nucleation and Growth: A Special Case



Summary - Nucleation and Growth



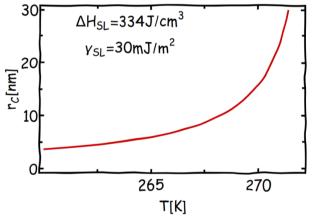
Nucleation Rate

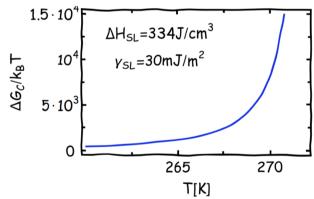
• Temperature dependence of $\Delta \textit{G}_{\mathsf{SL}}\left(\textit{T}\right) = \Delta \textit{H}_{\mathsf{SL}} - \textit{T}\Delta \textit{S}_{\mathsf{SL}}$

$$\Delta G_{\text{SL}}\left(\mathcal{T}_{\text{SL}}\right) = 0 \longrightarrow \Delta S_{\text{SL}} = \frac{\Delta H_{\text{SL}}}{\mathcal{T}_{\text{SL}}} \qquad \Delta G_{\text{SL}}\left(\mathcal{T}\right) = \Delta H_{\text{SL}}\left(1 - \mathcal{T}/\mathcal{T}_{\text{SL}}\right)$$

• Nucleation rate is Arrhenius-like - an example for ice nucleation

$$k = k_0 \exp{-\frac{\Delta G(r_c)}{k_B T}} = k_0 \exp{\left(-\frac{16\pi}{3k_B T}\gamma_{SL}^3 / \left(1 - \frac{T}{T_{SL}}\right)^2 \Delta H_{SL}^2\right)}$$

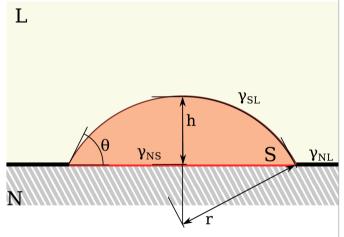




Heterogeneous Nucleation

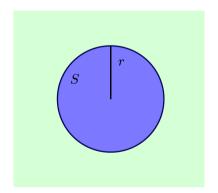
- Nucleation can also (and most often does!) happen at interfaces
- The shape of the critical nucleus is determined by a combination of Young equation, and the balance between solid-liquid surface energy and bulk free energy of phase transition.
- It is easy to see that if the solid has some affinity for the nucleus, the free-energy barrier for this process will be lower than homogeneous nucleation







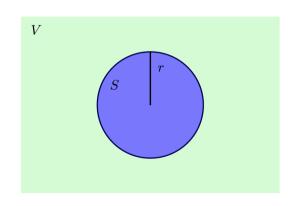
Melting Point Depression

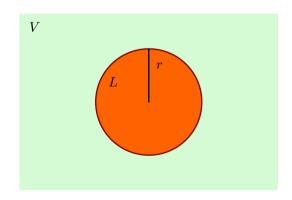


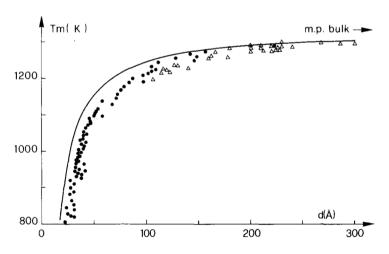


Melting Point Depression

$$rac{T}{T_{\mathsf{SL}}} = 1 - rac{3\left(\gamma_{\mathsf{SV}} - \gamma_{\mathsf{LV}}
ight)}{\Delta H_{\mathsf{SL}} r}$$







Conclusions

